Product data sheet

1 General description

The TJA1441 is a member of the TJA144x family of transceivers that provide an interface between a Controller Area Network (CAN) or CAN FD (Flexible Data rate) protocol controller and the physical two-wire CAN bus. TJA144x transceivers implement the CAN physical layer as defined in ISO 11898-2:2016 and SAE J2284-1 to SAE J2284-5, and are fully interoperable with high-speed Classical CAN and CAN FD transceivers. All TJA144x variants enable reliable communication in the CAN FD fast phase at data rates up to 5 Mbit/s.

The TJA1441 is intended as a simple replacement for high-speed Classical CAN and CAN FD transceivers, such as the TJA1051 or TJA1057 from NXP. It offers pin compatibility and is designed to avoid changes to hardware and software design, allowing the TJA1441 to be easily retrofitted to existing applications.

An AEC-Q100 Grade 0 variant, the TJR1441, is available for high temperature applications, supporting operation at 150 °C ambient temperature. A variant intended for industrial applications, the TJF1441, is also available.

1.1 TJA1441 variants

The TJA1441 comes in three variants, each available in an SO8 or HVSON8 package:

- The TJA1441A is a high-speed CAN transceiver with Normal and Silent modes and a VIO supply pin. The VIO pin allows for direct interfacing with 3.3 V and 5 V-supplied microcontrollers.
- The TJA1441B is a high-speed CAN transceiver with Normal and Silent modes.
- The TJA1441D is a high-speed CAN transceiver with Normal and Silent modes with a transmitter/receiver On/Off input.

2 Features and benefits

2.1 General

- ISO 11898-2:2016, SAE J2284-1 to SAE J2284-5 and SAE J1939-14 compliant
- Standard CAN and CAN FD data bit rates up to 5 Mbit/s
- Low Electromagnetic Emission (EME) and high Electromagnetic Immunity (EMI)
- Qualified according to AEC-Q100 Grade 1
- · Silent mode for node diagnosis and failure containment
- TJA1441A only: VIO input for interfacing with 3.3 V to 5 V microcontrollers
- TJA1441D only: dedicated input for switching to very low-current Off mode and disengaging from the bus
- All variants are available in SO8 and leadless HVSON8 (3.0 mm x 3.0 mm) packages; HVSON8 with improved Automated Optical Inspection (AOI) capability.



• Dark green product (halogen free and Restriction of Hazardous Substances (RoHS) compliant)

2.2 Predictable and fail-safe behavior

- Undervoltage detection with defined handling on all supply pins
- Full functionality guaranteed from the undervoltage detection thresholds up to the maximum limiting voltage values
- Defined behavior below the undervoltage detection thresholds
- Transceiver disengages from the bus (high-ohmic) when the supply voltage drops below the Off mode threshold
- Internal biasing of TXD and mode selection input pins, to enable defined fail-safe behavior

2.3 Protection

- High ESD handling capability on the bus pins (8 kV IEC and HBM)
- Bus pins protected against transients in automotive environments
- Transmit Data (TXD) dominant time-out function
- Thermally protected

3 Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CC}	supply voltage		4.5	-	5.5	V
I _{CC}	supply current	Normal mode, dominant	-	38	60	mA
		Normal mode, recessive	-	4	7	mA
		Silent mode	-	3	6	mA
		Off mode (TJA1441D only)	-	90	250	μA
V _{uvd(VCC)}	undervoltage detection voltage on pin VCC		4	-	4.5	V
V _{uvhys(VCC)}	undervoltage hysteresis voltage on pin VCC		50	-	-	mV
Vuvd(swoff)(VCC)	switch-off undervoltage detection voltage on pin VCC	TJA1441B/D	2.65	-	2.95	V
V _{IO}	supply voltage on pin VIO		2.95	-	5.5	V
I _{IO}	supply current on pin VIO	Normal mode, dominant; V _{TXD} = 0 V	-	250	760	μA
		Normal mode, recessive; $V_{TXD} = V_{IO}$	-	150	460	μA
		Silent mode; V _{TXD} = V _{IO}	-	70	200	μA
V _{uvd(swoff)(VIO)}	switch-off undervoltage detection voltage on pin VIO	TJA1441A	2.65	-	2.95	V
V _{ESD}	electrostatic discharge voltage	IEC 61000-4-2 on pins CANH and CANL	-8	-	+8	kV
V _{CANH}	voltage on pin CANH	limiting value according to IEC 60134	-36	-	+40	V
V _{CANL}	voltage on pin CANL	limiting value according to IEC 60134	-36	-	+40	V
T _{vj}	virtual junction temperature		-40	-	+150	°C

Ordering information 4

Table 2. Ordering	information		
Type number	Package		
	Name	Description	Version
TJA1441AT	SO8	plastic small outline package; 8 leads; body width 3.9 mm	SOT96-1
TJA1441BT			
TJA1441DT			
TJA1441ATK	HVSON8	plastic thermal enhanced very thin small outline package; no	SOT782-1
TJA1441BTK		leads; 8 terminals; body 3 × 3 × 0.85 mm	
TJA1441DTK			

Table 3. TJA1441 feature overview

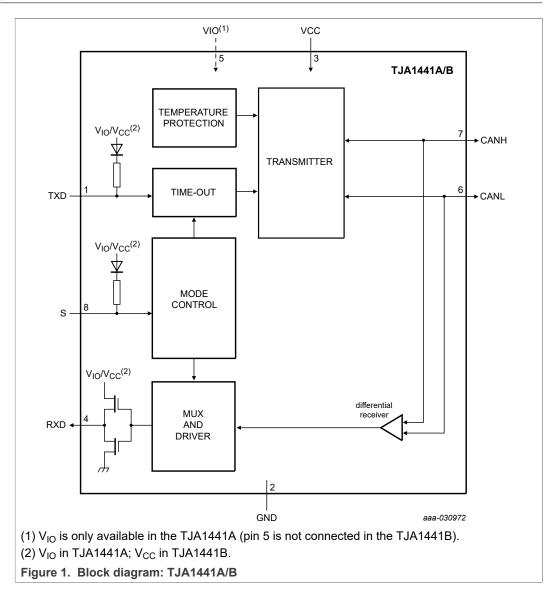
See Section 19 for a feature overview of the complete TJx144x/TJx146x/TJF1441 family.

	Mode	s				Supp	lies		Data	rate	Addit	ional fe	eatures	5		
Device ^[1]	Normal	Standby	Sleep	Silent/Listen-only	Selectable Off	VCC pin	VIO pin	VBAT pin	Up to 5 Mbit/s CAN FD	Up to 8 Mbit/s CAN FD	Signal improvement ^[2]	Wake-up source recognition ^[3]	Short WUP support [0.5 - 1.8 µs] ^[4]	Single supply pin wake-up	TXD dominant timeout	Local diagnostics via ERR_N pin
TJA1441A	•			•		•	•		•						•	
TJA1441B	•			•		•			•				1		•	
TJA1441D	•			•	•	•			•						•	

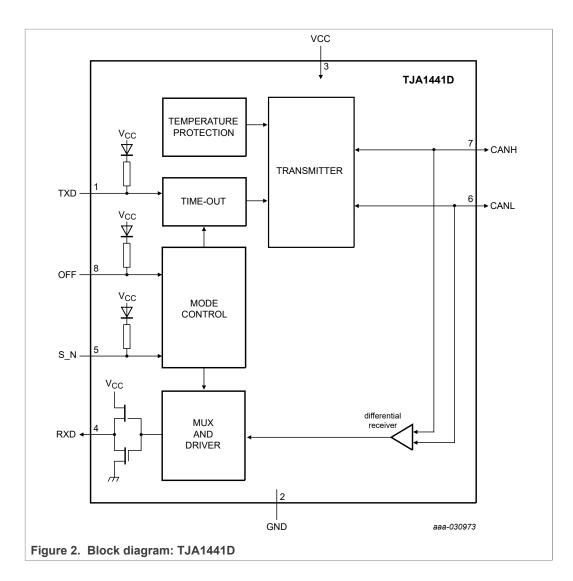
TJA1441 is AEC-Q100 Grade 1. CAN FD Signal Improvement Capability (SIC) according to CiA 601-4:2019. RXD is held LOW after wake-up request, enabling wake-up source recognition. WUP = wake-up pattern according ISO11898-2:2016. [1] [2] [3] [4]

High-speed CAN transceiver

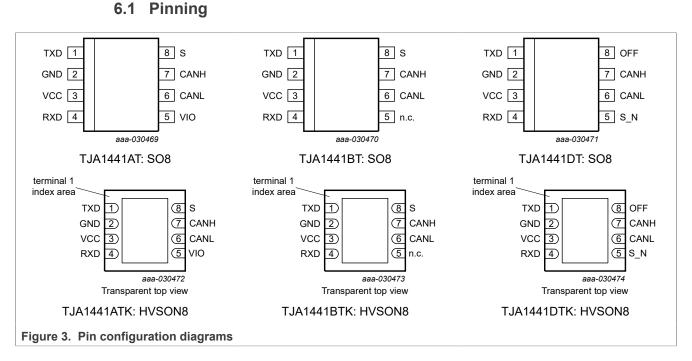
5 Block diagrams



High-speed CAN transceiver



6 **Pinning information**



6.2 Pin description

Table 4. Pin description

Symbol	Pin	Type ^[1]	Description
TXD	1	I	transmit data input; inputs data (from the CAN controller) to be written to the bus lines
GND ^[2]	2	G	ground
VCC	3	Р	5 V supply voltage input
RXD	4	0	receive data output; outputs data read from the bus lines (to the CAN controller).
VIO	5	Р	supply voltage input for I/O level adapter in TJA1441A
n.c.		-	not connected in TJA1441B
S_N		I	Silent mode control input in TJA1441D; active-LOW
CANL	6	AIO	LOW-level CAN bus line
CANH	7	AIO	HIGH-level CAN bus line
S	8	I	Silent mode control input in TJA1441A and TJA1441B; active-HIGH
OFF		I	Off mode control input in TJA1441D; active-HIGH

[1] I: digital input; O: digital output; AIO: analog input/output; P: power supply; G: ground.

[2] HVSON package die supply ground is connected to both the GND pin and the exposed center pad. The GND pin must be soldered to board ground. For enhanced thermal and electrical performance, it is also recommended to solder the exposed center pad to board ground.

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7 Functional description

7.1 Operating modes

The TJA1441 supports three operating modes, Normal, Silent and Off. The operating mode is selected via pin S in the TJA1441A/B and via pins S_N and OFF in the TJA1441D. See <u>Table 5</u> and <u>Table 6</u> for a description of the operating modes under normal supply conditions. Mode changes are completed after transition time $t_{t(moch)}$.

Table 5.	Operating	modes:	TJA1441A/B
10010 01	oporating		

Mode	Inputs		Outputs	
	Pin S	Pin TXD	CAN driver	Pin RXD
Normal	LOW			LOW
				LOW when bus dominant
				HIGH when bus recessive
Silent	HIGH	Х	biased to V _{CC} /2	LOW when bus dominant
				HIGH when bus recessive
Off ^[1]	Х	Х	high-ohmic state	high-ohmic state

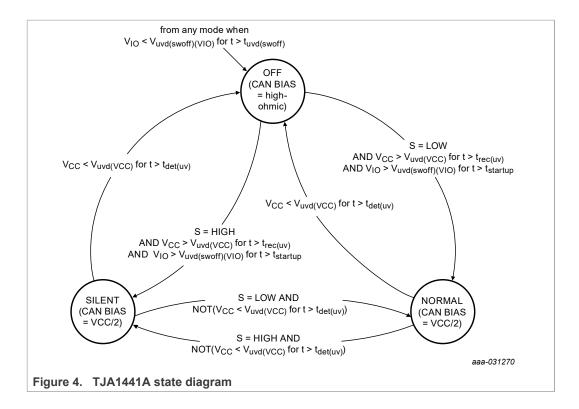
 Off mode is only entered when the voltage on supply pin VCC or VIO (TJA1441A) is below any undervoltage detection threshold (see Figure 4 and Figure 5).

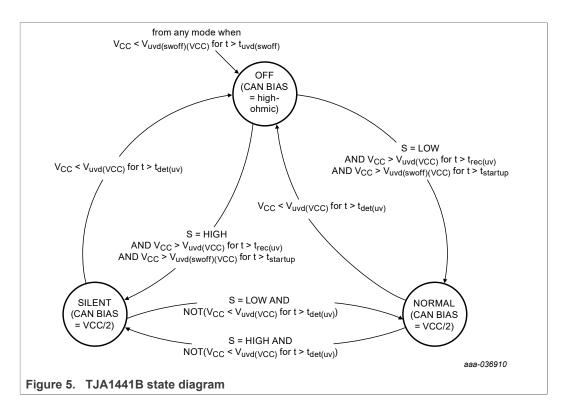
Table 6.	Operating modes: TJ	IA1441D
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Mode	Inputs			Outputs	
	Pin S_N	Pin OFF	Pin TXD	CAN driver	Pin RXD
Normal	HIGH	LOW	LOW	dominant	LOW
			HIGH	recessive	LOW when bus dominant
					HIGH when bus recessive
Silent	LOW	LOW	Х	biased to V _{CC} /2	LOW when bus dominant
					HIGH when bus recessive
Off ^[1]	Х	HIGH	Х	high-ohmic state	high-ohmic state

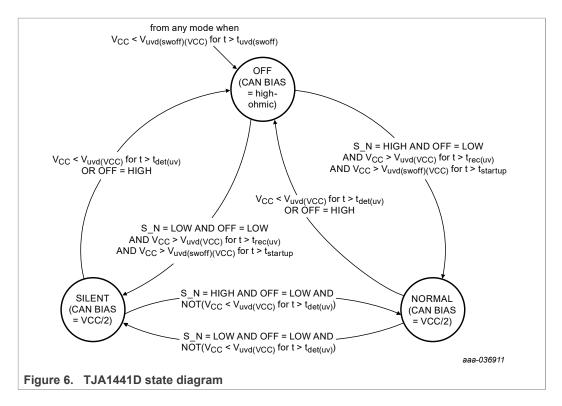
[1] Off mode is also entered when the voltage on supply pin VCC is below the undervoltage detection threshold (see Figure 6).

High-speed CAN transceiver





High-speed CAN transceiver



7.1.1 Off mode

The TJA1441 switches to Off mode from any mode when the supply voltage on pin VIO/VCC falls below the switch-off undervoltage detection threshold ($V_{uvd(swoff)(VIO)}$ in TJA1441A; $V_{uvd(swoff)(VCC)}$ in TJA1441B/D) or when V_{CC} drops below $V_{uvd(VCC)}$. This is the default mode when the supply is first connected.

The CAN pins and pin RXD are in a high-ohmic state in Off mode.

When the supply voltage rises above the switch-off undervoltage detection threshold, the TJA1441 starts to boot up, triggering an initialization procedure. It switches to the selected mode after $\underline{t_{startup}}$, provided $V_{CC} > V_{uvd(VCC)}$.

7.1.2 Silent mode

A HIGH level on pin S selects Silent mode in the TJA1441A and TJA1441B.

A LOW level on pins S_N and OFF selects Silent mode in the TJA1441D.

The transmitter is disabled in Silent mode, releasing the bus pins to $V_{CC}/2$. All other IC functions, including the receiver, continue to operate as in Normal mode. Silent mode can be used to prevent a faulty CAN controller disrupting network communications.

7.1.3 Normal mode

A LOW level on pin S selects Normal mode in the TJA1441A and TJA1441B.

A HIGH level on pin S_N and a LOW level on pin OFF selects Normal mode in the TJA1441D.

In Normal mode, the transceiver can transmit and receive data via bus lines CANH and CANL. Pin TXD must be HIGH at least once in Normal mode before transmission can

begin. The differential receiver converts the analog data on the bus lines into digital data on pin RXD. The slopes of the output signals on the bus lines are controlled internally and are optimized in a way that guarantees the lowest possible EME. In recessive state, the output voltage on the bus pins is $V_{CC}/2$.

7.1.4 Controlled Off mode (TJA1441D)

A HIGH level on pin OFF selects Off mode. In Off mode the entire transceiver is disabled, allowing the microcontroller to save power when CAN communication is not required. The bus pins are high-ohmic in Off mode, making the transceiver invisible to the rest of the network.

7.1.5 Operating modes and gap-free operation

Gap-free operation guarantees defined behavior at all voltage levels. Supply voltageto-operating mode mapping is detailed in <u>Figure 7</u> and in the state diagrams (<u>Figure 4</u>, <u>Figure 5</u> and <u>Figure 6</u>).

	TJA1441A						TJA1441B/D	
	5.5 V - 6 V ^[1]			Fully functional	[2][3]		5.5 V - 6 V ^[1]	Fully functional ^{[2][3]}
e on VCC	V _{CC} operating range (4.5 V - 5.5 V)		Fully functional ^{[2][3]} OR Off ^[4] Fully functional ^[2] and characteristics guaranteed ^[5] 5		V _{CC} operating range (4.5 V - 5.5 V)	Fully functional ^[2] AND characteristics guaranteed ^[5]		
Voltage range on VCC	V _{uvd(VCC)} range ^[6]	Off	Fully functional ^[2] OR Off ^[4]	Fully functional ^[2] Ol Off ^[4]	२	Voltage range on VCC	V _{uvd(VCC)} range	Fully functional ^[2] OR Off ^[4]
Volt						Volt	2.95 V - 4 V	Off
	-0.3 V - 4 V		Off ^[4]	Off			V _{uvd(swoff)(VCC)} range	Off ^[4]
							-0.3 V - 2.65 V	Off
		-0.3 V - 2.65 V	V _{uvd} (swoff)(VIO) range ^[6]	V _{IO} operating range (2.95 V - 5.5 V)	5.5 V - 6 V ^[1]			
			Voltage ra	nge on VIO				
[2 [3 [4	characteristics, function functionality cannot be Target transceiver func Prolonged operation of characteristics are gua For a given value of V _C thresholds (V _{uvd(VCC)} , in this data sheet). To g minimum thresholds sp Datasheet characterist characteristics tables. The following applies to - The device is fully fun	nality of guara tionali the do rantee C (and Vuvd(s uaran ecifice ics are o TJA1 nction	or performance may occur nteed. ty as described in this da evice outside the operatin d provided the AMR has d V _{IO} in TJA1441A), a spe woff)(VIO) and V _{UVd} (swoff)(tee the device will be in a d for these undervoltage of e guaranteed within the V _I 441A: al when both V _{CC} and V _{IC}	r. Returning from above A tasheet is applicable. Ig range may impact relial not been exceeded. cific device will be in a sin (v_{CC}) . The actual thresho specific state, V_{IO} and V_{I} detection ranges.	MR to bility ov gle def lds car CC mus ges. Ex	the op ver life ined s n vary st be e ceptic	s table). Above the AMR, ir perating range, datasheet time. Returning to the ope state determined by its und between devices (within ti ither above the maximum ons are described in the St	characteristics and rating range, datasheet lervoltage detection he ranges specified or below the

Figure 7. Supply voltage ranges and gap-free operation

7.2 Fail-safe features

7.2.1 TXD dominant time-out function

A 'TXD dominant time-out' timer is started when pin TXD is set LOW. If the LOW state on this pin persists for longer than $\underline{t_{to(dom)TXD}}$, the transmitter is disabled, releasing the bus lines to recessive state. This function prevents a hardware and/or software application failure from driving the bus lines to a permanent dominant state (blocking all network communications). The TXD dominant time-out timer is reset when pin TXD goes HIGH.

7.2.2 Internal biasing of TXD and mode input pins

Pins TXD, S, S_N and OFF have internal pull-ups to V_{CC}/V_{IO} to ensure a safe, defined state in case one or more of these pins is left open or become floating. Pull-up resistors

are active on these pins in all states; they should be held at the V_{CC}/V_{IO} level in Silent (or Off in TJA1441D) mode to minimize supply current.

7.2.3 Undervoltage detection on pins VCC and VIO

If V_{CC} or V_{IO} drops below the undervoltage detection threshold (V_{uvd(VCC)} or V_{uvd(swoff)VCC} for V_{CC}; V_{uvd(swoff)VIO} for V_{IO}) the transceiver switches to Off mode and disengages from the bus (zero load; bus pins high-ohmic) until the supply voltage has recovered. If Normal mode is selected, the output drivers are enabled once both V_{CC} and V_{IO} are again within their operating ranges and TXD has been reset to HIGH.

7.2.4 Overtemperature protection

The device is protected against overtemperature conditions. If the junction temperature exceeds the shutdown junction temperature, $T_{j(sd)}$, the CAN bus drivers are disabled. When the junction temperature drops below $T_{j(sd)rel}$, the CAN bus drivers recover once TXD has been reset to HIGH and Normal mode is selected (waiting for TXD to go HIGH prevents output driver oscillation due to small variations in temperature).

7.2.5 I/O levels

Pin VIO of the TJA1441A should be connected to the microcontroller supply voltage (see <u>Figure 11</u>). This adjusts the signal levels on pins TXD, RXD and S to the I/O levels of the microcontroller, allowing for direct interfacing without additional glue logic.

All I/O levels are related to V_{CC} in the TJA1441B/D and are, therefore, compatible with 5 V microcontrollers. Spurious signals from the microcontroller on pins S, S_N and OFF are filtered out with a filter time of $\underline{t_{fitr(IO)}}$.

Limiting values 8

Table 7. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134); all voltages are referenced to pin GND, unless otherwise specified.

Symbol	Parameter	Conditions		Min	Мах	Unit
V _x	voltage on pin x ^[1]	on pins VCC, VIO (TJA1441A), TXD, S		-0.3	+6	V
		(TJA1441A/B), OFF (TJA1441D), S_N (TJA1441D)		-	+7 ^[2]	
		on pins CANH, CANL		-36	+40	V
		on pins RXD				
		TJA1441A		-0.3	V _{IO} +0.3 ^[3]	V
		TJA1441B, TJA1441D		-0.3	V _{CC} +0.3 ^[3]	V
V _(CANH-CANL)	voltage between pin CANH and pin CANL			-40	+40	V
V _{trt}	transient voltage	on pins CANH, CANL	[4]			
		pulse 1		-100	-	V
		pulse 2a		-	+75	V
		pulse 3a		-150	-	V
		pulse 3b		-	+100	V
V _{ESD}	electrostatic discharge	IEC 61000-4-2 (150 pF, 330 Ω discharge circuit)	[5]			
	voltage	on pins CANH, CANL		-8	+8	kV
		Human Body Model (HBM)				
		on any pin	[6]	-4	+4	kV
		on pins CANH, CANL	[7]	-8	+8	kV
		Charged Device Model (CDM)	[8]			
		on corner pins		-750	+750	V
		on any other pin		-500	+500	V
T _{vj}	virtual junction temperature		[9]	-40	+150	°C
T _{stg}	storage temperature		[10]	-55	+150	°C

The device can sustain voltages up to the specified values over the product lifetime, provided applied voltages (including transients) never exceed these [1] values

[2] [3] The device can withstand voltages between 6 V and 7 V for a total of 20 s over the product lifetime.

Subject to the qualifications detailed in Table notes 1 and 2 above for pins VCC, VIO, TXD, S, OFF, and S_N. Verified by an external test house according to IEC TS 62228, Section 4.2.4; parameters for standard pulses defined in ISO7637. Verified by an external test house according to IEC TS 62228, Section 4.3. [4] [5]

According to AEC-Q100-002. [6]

Pins stressed to reference group containing all ground and supply pins, emulating the application circuits (Figure 11, Figure 12 and Figure 13). HBM pulse as specified in AEC-Q100-002 used. [7]

According to AEC-Q100-011. [8]

In accordance with IEC 60747-1. An alternative definition of virtual junction temperature is: $T_{vj} = T_{amb} + P \# R_{th(j-a)}$, where $R_{th(j-a)}$ is a fixed value used in the calculation of T_{vj} . The rating for T_{vj} limits the allowable combinations of power dissipation (P) and ambient temperature (T_{amb}). T_{stg} in application according to IEC61360-4. For component transport and storage conditions, see instead IEC61760-2. [9]

[10]

Thermal characteristics 9

Table 8. Thermal characteristics

Value determined for free convection conditions on a JEDEC 2S2P board.

Symbol	Parameter	Conditions ^[1]	Тур	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	SO8	96	K/W
		HVSON8	57	K/W
R _{th(j-c)}	thermal resistance from junction to case ^[2]	HVSON8	19	K/W
Ψ_{j-top}	thermal characterization parameter from junction to top of package	SO8	9	K/W
		HVSON8	9	K/W

According to JEDEC JESD51-2, JESD51-5 and JESD51-7 at natural convection on 2s2p board. Board with two inner copper layers (thickness: 35 µm) [1] and thermal via array under the exposed pad connected to the first inner copper layer (thickness: 70 μ m). Case temperature refers to the center of the heatsink at the bottom of the package.

[2]

10 Static characteristics

Table 9. Static characteristics

 T_{vj} = -40 °C to +150 °C; V_{CC} = 4.5 V to 5.5 V; V_{IO} = 2.95 V to 5.5 V (TJA1441A); R_L = 60 Ω ; unless specified otherwise; all voltages are defined with respect to ground; positive currents flow into the IC.^[1]

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
Supply; pin V	VCC	'		1		
V _{CC}	supply voltage		4.5	-	5.5	V
V _{uvd}	undervoltage detection voltage	[2	4	-	4.5	V
V _{uvhys}	undervoltage hysteresis voltage		50	-	-	mV
V _{uvd(swoff)}	switch-off undervoltage detection voltage	TJA1441B/D [2	2.65	-	2.95	V
I _{CC}	supply current	Normal mode				
		dominant; V _{TXD} = 0 V; t < t _{to(dom)TXD}	-	38	60	mA
		dominant; V _{TXD} = 0 V; short circuit on bus lines; -3 V < (V _{CANH} = V _{CANL}) < +40 V	-	-	125	mA
		recessive; $V_{TXD} = V_{IO}^{[3]}$	-	4	7	mA
		Silent mode; $V_{TXD} = V_{IO}^{[3]}$	-	3	6	mA
		Off mode; (TJA1441D only)	-	90	250	μA
I/O level ada	apter supply; pin VIO (TJA144	1A)				
V _{IO}	supply voltage		2.95	-	5.5	V
V _{uvd(swoff)}	switch-off undervoltage detection voltage		2.65	-	2.95	V
I _{IO}	supply current	Normal mode; dominant; V _{TXD} = 0 V	-	250	760	μA

Vu		switch-off undervoltage detection voltage		2.65	-	2.95	'
I _{IO})	supply current	Normal mode; dominant; V_{TXD} = 0 V	-	250	760	1
			Normal mode; recessive; $V_{TXD} = V_{IO}$	-	150	460	ł
			Silent mode; V _{TXD} = V _{IO}	-	70	200	ł

μA μA

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Table 9. Static characteristics...continued

 T_{vj} = -40 °C to +150 °C; V_{CC} = 4.5 V to 5.5 V; V_{IO} = 2.95 V to 5.5 V (TJA1441A); R_L = 60 Ω ; unless specified otherwise; all voltages are defined with respect to ground; positive currents flow into the IC.^[1]

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
CAN transm	nit data input; pin TXD					
V _{IH}	HIGH-level input voltage		0.7V _{IO} [3	^{;]} -	-	V
V _{IL}	LOW-level input voltage		-	-	0.3V _{IO} ^[3]	V
V _{hys(TXD)}	hysteresis voltage on pin TXD		50	-	-	mV
R _{pu}	pull-up resistance		20	-	80	kΩ
Ci	input capacitance	[4	^{1]} -	-	10	pF
CAN receiv	e data output; pin RXD		·	·		
I _{OH}	HIGH-level output current	$V_{RXD} = V_{IO}^{[3]} - 0.4 V$	-10	-	-1	mA
I _{OL}	LOW-level output current	V _{RXD} = 0.4 V	+1	-	+10	mA
Silent contr	rol inputs; pins S (TJA1441A/B)	, S_N (TJA1441D) and OFF (TJA1441D)				,
V _{IH}	HIGH-level input voltage		0.7V _{IO} [3	-	-	V
V _{IL}	LOW-level input voltage		-	-	0.3V _{IO} ^[3]	V
V _{hys}	hysteresis voltage		50	-	-	mV
R _{pu}	pull-up resistance		20	-	80	kΩ
Ci	input capacitance	[4	^{1]} -	-	10	pF
Bus lines; pi	ins CANH and CANL	·				
V _{O(dom)}	dominant output voltage	V_{TXD} = 0 V; t < t _{to(dom)TXD} ; $V_{CC} \ge 4.75$ V				
		pin CANH; R_L = 50 Ω to 65 Ω	2.75	3.5	4.5	V
		pin CANL; R_L = 50 Ω to 65 Ω	0.5	1.5	2.25	V
V _{TXsym}	transmitter voltage symmetry	$V_{TXsym} = V_{CANH} + V_{CANL};$ $C_{SPLIT} = 4.7 \text{ nF};$ $f_{TXD} = 250 \text{ kHz}, 1 \text{ MHz or } 2.5 \text{ MHz}$	^{1]} 0.9V _{CC}	-	1.1V _{CC}	V
V _{cm(step)}	common mode voltage step	[4 [1 [6	5]	-	+150	mV
V _{cm(p-p)}	peak-to-peak common mode voltage		^{4]} -300	-	+300	mV
V _{O(dif)}	differential output voltage	dominant; Normal mode; $V_{TXD} = 0 V$; t < $t_{to(dom)TXD}$; $V_{CC} \ge 4.75 V$				
		$R_L = 50 \ \Omega$ to 65 Ω	1.5	-	3	V
		R_L = 45 Ω to 70 Ω	1.4	-	3.3	V
		R _L = 2240 Ω ^{[4}	^{I]} 1.5	-	5	V
		recessive; no load				
		Normal or Silent mode; V _{TXD} = V _{IO} ^[3]	-50	-	+50	mV

Table 9. Static characteristics...continued

 T_{vj} = -40 °C to +150 °C; V_{CC} = 4.5 V to 5.5 V; V_{IO} = 2.95 V to 5.5 V (TJA1441A); R_L = 60 Ω ; unless specified otherwise; all voltages are defined with respect to ground; positive currents flow into the IC.^[1]

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
V _{O(rec)}	recessive output voltage	Normal or Silent mode; V _{TXD} = V _{IO} ^[3] ; no load	2	2.5	3	V
$V_{th(RX)dif}$	differential receiver threshold voltage	Normal or Silent mode; -12 V \leq V _{CANH} \leq +12 V; -12 V \leq V _{CANL} \leq +12 V	0.5	-	0.9	V
V _{rec(RX)}	receiver recessive voltage	Normal or Silent mode; -12 V \leq V _{CANH} \leq +12 V; -12 V \leq V _{CANL} \leq +12 V	-4	-	0.5	V
V _{dom(RX)}	receiver dominant voltage	Normal or Silent mode; -12 V \leq V _{CANH} \leq +12 V; -12 V \leq V _{CANL} \leq +12 V	0.9	-	9	V
V _{hys(RX)} dif	differential receiver hysteresis voltage	Normal or Silent mode; -12 V \leq V _{CANH} \leq +12 V; -12 V \leq V _{CANL} \leq +12 V	50	-	-	mV
I _{O(sc)}	short-circuit output current	$\begin{array}{l} -15 \ V \leq V_{CANH} \leq +40 \ V; \\ -15 \ V \leq V_{CANL} \leq +40 \ V \end{array}$	-	-	115	mA
I _{O(sc)rec}	recessive short-circuit output current	Normal mode; $V_{TXD} = V_{IO}^{[3]}$; -27 V $\leq V_{CANH} \leq$ +32 V; -27 V $\leq V_{CANL} \leq$ +32 V	-3	-	+3	mA
IL	leakage current	$V_{CC} = V_{IO} = 0 V$ or pins shorted to GND via 47 K Ω ; $V_{CANH} = V_{CANL} = 5 V$;	-10	-	+10	μA
R _i	input resistance	$\begin{array}{l} -2 \ V \leq V_{CANL} \leq +7 \ V; \\ -2 \ V \leq V_{CANH} \leq +7 \ V \end{array}$	25	40	50	kΩ
ΔR _i	input resistance deviation	$0 \text{ V} \le \text{V}_{\text{CANL}} \le +5 \text{ V}; 0 \text{ V} \le \text{V}_{\text{CANH}} \le +5 \text{ V}$	-3	-	+3	%
R _{i(dif)}	differential input resistance	$\begin{array}{l} -2 \ V \leq V_{CANL} \leq +7 \ V; \\ -2 \ V \leq V_{CANH} \leq +7 \ V \end{array}$	50	80	100	kΩ
C _{i(cm)}	common-mode input capacitance	[4]	-	-	20	pF
C _{i(dif)}	differential input capacitance	[4]	-	-	10	pF
Temperature	detection				1	
$T_{j(sd)}$	shutdown junction temperature		180	-	200	°C
T _{j(sd)rel}	release shutdown junction temperature		175	-	195	°C

[1] All parameters are guaranteed over the virtual junction temperature range by design. Factory testing uses correlated test conditions to cover the specified temperature and power supply voltage range.

[2] Undervoltage is detected between min and max values. Undervoltage is guaranteed to be detected below min value and guaranteed not to be detected above max value.

[3] V_{CC} in TJA1441B/D

[4] Not tested in production; guaranteed by design.

[5] The test circuit used to measure the bus output voltage symmetry (which includes C_{SPLIT}) is shown in Figure 15

[6] See Figure 10

11 Dynamic characteristics

Table 10. Dynamic characteristics

 $T_{vj} = -40$ °C to +150 °C; $V_{CC} = 4.5$ V to 5.5 V; $V_{IO} = 2.95$ V to 5.5 V (TJA1441A); $R_L = 60 \Omega$; unless specified otherwise. All voltages are defined with respect to ground.^[1]

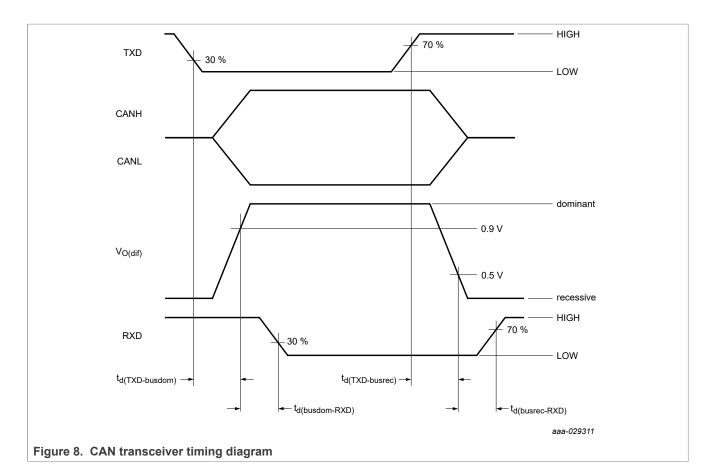
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
CAN timing cl	naracteristics; t _{bit(TXD)} ≥ 200 ns; see <u>Figure</u>	8, <u>Figure 9</u> and <u>Figure 14</u>		1			
t _{d(TXD-busdom)}	delay time from TXD to bus dominant	Normal mode		-	-	102.5	ns
t _{d(TXD-busrec)}	delay time from TXD to bus recessive	Normal mode		-	-	102.5	ns
t _{d(busdom-RXD)}	delay time from bus dominant to RXD	Normal or Silent mode		-	-	115	ns
t _{d(busrec-RXD)}	delay time from bus recessive to RXD	Normal or Silent mode		-	-	115	ns
t _{d(TXDL-RXDL)}	delay time from TXD LOW to RXD LOW	Normal mode		-	-	215	ns
t _{d(TXDH-RXDH)}	delay time from TXD HIGH to RXD HIGH	Normal mode		-	-	215	ns
CAN FD timin	g characteristics; see <u>Figure 9</u> and <u>Figure </u>	14		1	1		
t _{bit(bus)}	transmitted recessive bit width	t _{bit(TXD)} = 500 ns		435	-	530	ns
		t _{bit(TXD)} = 200 ns		155	-	210	ns
t _{bit(RXD)} bit time on pin RXD		t _{bit(TXD)} = 500 ns	400	-	550	ns	
		t _{bit(TXD)} = 200 ns		120	-	220	ns
∆t _{rec}	receiver timing symmetry	t _{bit(TXD)} = 500 ns		-65	-	40	ns
		t _{bit(TXD)} = 200 ns		-45	-	15	ns
Dominant time	e-out time; pin TXD	1		1		1	
<u>t_{to(dom)}TXD</u>	TXD dominant time-out time	V _{TXD} = 0 V; Normal mode	[2] [3]	0.8	-	9	ms
Mode transitio	ons			1			
<u>t_{t(moch)}</u>	mode change transition time		[2]	-	-	50	μs
<u>t_{startup}</u>	start-up time		[2]	-	-	1	ms
IO filter; pins	S (TJA1441A/B), S_N (TJA1441D) and OFI	F (TJA1441D)					
<u>t_{fitr(IO)}</u>	I/O filter time		[4]	1	-	5	μs
Undervoltage	detection; see Figure 4, Figure 5 and Figur	<u>e 6</u>		1			
t _{det(uv)}	undervoltage detection time	on pin VCC	[2]	-	-	30	μs
t _{uvd(swoff)}	switch-off undervoltage detection time	on pin VCC; TJA1441B/D	[2]	-	-	30	μs
		on pin VIO; TJA1441A	[2]	-	-	30	μs
t _{rec(uv)}	undervoltage recovery time	on pin VCC	[2]	-	-	50	μs
	1						

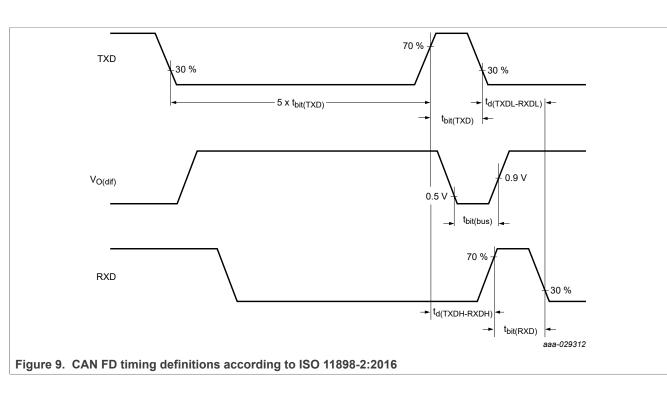
[1] All parameters are guaranteed over the junction temperature range by design. Factory testing uses correlated test conditions to cover the specified temperature and power supply voltage ranges.

[2] Not tested in production; guaranteed by design.
 [3] Time-out occurs between the min and max values. Time-out is guaranteed not to occur below the min value; time-out is guaranteed to occur above the max value.

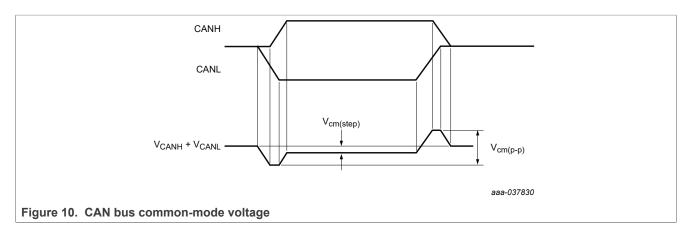
[4] Pulses shorter than the min value are guaranteed to be filtered out; pulses longer than the max value are guaranteed to be processed.

High-speed CAN transceiver



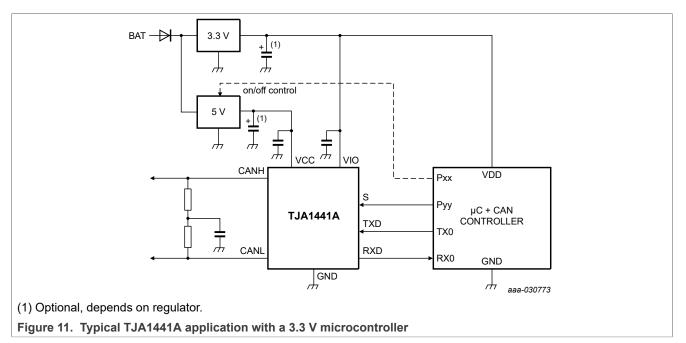


High-speed CAN transceiver



12 Application information

12.1 Application diagrams



High-speed CAN transceiver

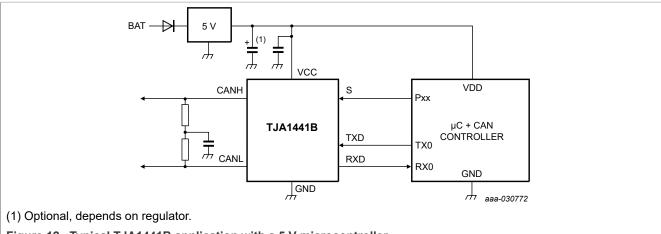
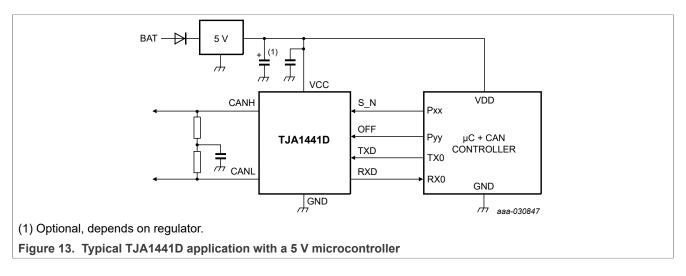


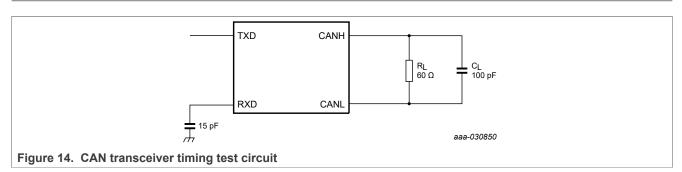
Figure 12. Typical TJA1441B application with a 5 V microcontroller

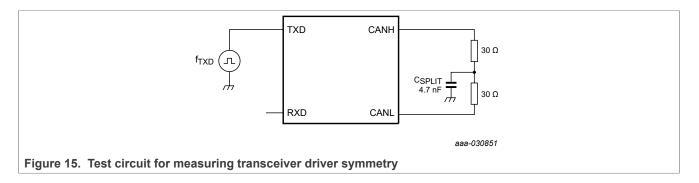


12.2 Application hints

Further information on the application of the TJA1441 can be found in NXP application hints AH2002 '*TJx144x/TJx146x Application Hints*', available on request from NXP Semiconductors.

13 Test information





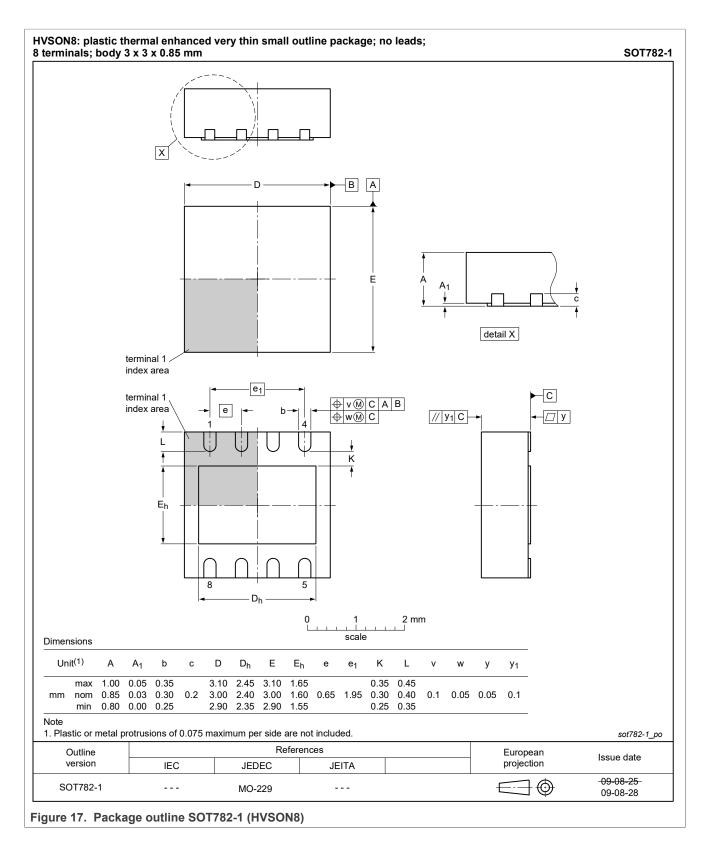
13.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q100 Rev-H - Failure mechanism based stress test qualification for integrated circuits*, and is suitable for use in automotive applications.

14 Package outline

	stic s	mall c	outline	e pacl	kage;	8 lead	s; bo	dy wi	dth 3.	9 mm							5	от96
				Ty	D -		- -		c t			- E						
			- - 2 8				5											
			1	pin 1 in			- + 4 bp	→ w (M)				detail			Α ↓ θ			
							0		2.5 scale		5 mm	1						
	Α					rom the		I mm di E ⁽²⁾	scale		5 mm		Q	v	w	у	Z ⁽¹⁾	θ
		A ₁ 0.25	A₂ 1.45	Α3	b _p 0.49	c 0.25	origina D ⁽¹⁾ 5.0	E⁽²⁾ 4.0	scale mensio	Н _Е 6.2	I	L р 1.0	0.7	v 0.25	w 0.25	y 0.1	0.7	
DIMENS UNIT mm inches	A max.	A ₁	A ₂ 1.45 1.25 0.057		b _p 0.49 0.36 0.019	c	origina D ⁽¹⁾	E ⁽²⁾	scale mensio	HE	L	L _p 1.0 0.4 0.039	0.7 0.6 0.028				_	θ 8° 0°
UNIT mm inches Notes	A max. 1.75 0.069	A ₁ 0.25 0.10 0.010 0.004	A ₂ 1.45 1.25 0.057 0.049 sions of	A ₃ 0.25 0.01	b _p 0.49 0.36 0.019 0.014 m (0.000	c 0.25 0.19 0.0100	origina D ⁽¹⁾ 5.0 4.8 0.20 0.19	E ⁽²⁾ 4.0 3.8 0.16 0.15	scale mensio e 1.27 0.05	H _E 6.2 5.8 0.244 0.228	L 1.05 0.041 ed.	Lp 1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3 0.028	8°
UNIT mm inches Notes I. Plastic 2. Plastic	A max. 1.75 0.069	A ₁ 0.25 0.10 0.010 0.004	A ₂ 1.45 1.25 0.057 0.049 sions of	A ₃ 0.25 0.01	b _p 0.49 0.36 0.019 0.014 m (0.000	c 0.25 0.19 0.0100 0.0075	origina D ⁽¹⁾ 5.0 4.8 0.20 0.19 maximum	E ⁽²⁾ 4.0 3.8 0.16 0.15	scale mensio e 1.27 0.05 de are no e are no	H _E 6.2 5.8 0.244 0.228	L 1.05 0.041 ed.	L _p 1.0 0.4 0.039	0.7 0.6 0.028 0.024	0.25	0.25 0.01 PEAN	0.1	0.7 0.3 0.028	8° 0°

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TJA1441 Product data sheet

15 Handling information

All input and output pins are protected against ElectroStatic Discharge (ESD) under normal handling. When handling ensure that the appropriate precautions are taken as described in *JESD625-A* or equivalent standards.

16 Soldering of SMD packages

This text provides a very brief insight into a complex technology. A more in-depth account of soldering ICs can be found in Application Note *AN10365 "Surface mount reflow soldering description"*.

16.1 Introduction to soldering

Soldering is one of the most common methods through which packages are attached to Printed Circuit Boards (PCBs), to form electrical circuits. The soldered joint provides both the mechanical and the electrical connection. There is no single soldering method that is ideal for all IC packages. Wave soldering is often preferred when through-hole and Surface Mount Devices (SMDs) are mixed on one printed wiring board; however, it is not suitable for fine pitch SMDs. Reflow soldering is ideal for the small pitches and high densities that come with increased miniaturization.

16.2 Wave and reflow soldering

Wave soldering is a joining technology in which the joints are made by solder coming from a standing wave of liquid solder. The wave soldering process is suitable for the following:

- Through-hole components
- Leaded or leadless SMDs, which are glued to the surface of the printed circuit board

Not all SMDs can be wave soldered. Packages with solder balls, and some leadless packages which have solder lands underneath the body, cannot be wave soldered. Also, leaded SMDs with leads having a pitch smaller than ~0.6 mm cannot be wave soldered, due to an increased probability of bridging.

The reflow soldering process involves applying solder paste to a board, followed by component placement and exposure to a temperature profile. Leaded packages, packages with solder balls, and leadless packages are all reflow solderable.

Key characteristics in both wave and reflow soldering are:

- Board specifications, including the board finish, solder masks and vias
- Package footprints, including solder thieves and orientation
- · The moisture sensitivity level of the packages
- Package placement
- Inspection and repair
- Lead-free soldering versus SnPb soldering

16.3 Wave soldering

Key characteristics in wave soldering are:

- Process issues, such as application of adhesive and flux, clinching of leads, board transport, the solder wave parameters, and the time during which components are exposed to the wave
- · Solder bath specifications, including temperature and impurities

16.4 Reflow soldering

Key characteristics in reflow soldering are:

- Lead-free versus SnPb soldering; note that a lead-free reflow process usually leads to higher minimum peak temperatures (see <u>Figure 18</u>) than a SnPb process, thus reducing the process window
- Solder paste printing issues including smearing, release, and adjusting the process window for a mix of large and small components on one board
- Reflow temperature profile; this profile includes preheat, reflow (in which the board is heated to the peak temperature) and cooling down. It is imperative that the peak temperature is high enough for the solder to make reliable solder joints (a solder paste characteristic). In addition, the peak temperature must be low enough that the packages and/or boards are not damaged. The peak temperature of the package depends on package thickness and volume and is classified in accordance with <u>Table 11</u> and <u>Table 12</u>

Table 11. SnPb eutectic process (from J-STD-020D)

Package thickness (mm)	Package reflow temperature (°C) Volume (mm³)						
	< 350	≥ 350					
< 2.5	235	220					
≥ 2.5	220	220					

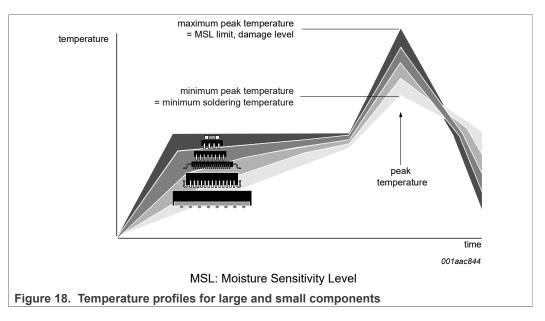
Table 12. Lead-free process (from J-STD-020D)

Package thickness (mm)	Package reflow temperature (°C)							
	Volume (mm ³)							
	< 350	> 2000						
< 1.6	260	260	260					
1.6 to 2.5	260	250	245					
> 2.5	250	245	245					

Moisture sensitivity precautions, as indicated on the packing, must be respected at all times.

Studies have shown that small packages reach higher temperatures during reflow soldering, see <u>Figure 18</u>.

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For further information on temperature profiles, refer to Application Note *AN10365 "Surface mount reflow soldering description"*.

17 Soldering of HVSON packages

<u>Section 16</u> contains a brief introduction to the techniques most commonly used to solder Surface Mounted Devices (SMD). A more detailed discussion on soldering HVSON leadless package ICs can be found in the following application note:

• AN10365 "Surface mount reflow soldering description"

18 Appendix: ISO 11898-2:2016 parameter cross-reference list

ISO 11898-2:2016		NXP data sheet			
Parameter	Notation	Symbol	Parameter		
HS-PMA dominant output characteristics					
Single ended voltage on CAN_H	V _{CAN_H}	V _{O(dom)}	dominant output voltage		
Single ended voltage on CAN_L	V _{CAN_L}	_			
Differential voltage on normal bus load	V _{Diff}	V _{O(dif)}	differential output voltage		
Differential voltage on effective resistance during arbitration]				
Optional: Differential voltage on extended bus load range	-				
HS-PMA driver symmetry					
Driver symmetry	V _{SYM}	V _{TXsym}	transmitter voltage symmetry		
Maximum HS-PMA driver output current					
Absolute current on CAN_H	I _{CAN_H}	I _{O(sc)dom}	dominant short-circuit output		
Absolute current on CAN_L	I _{CAN_L}		current		
HS-PMA recessive output characteristics, bus biasing ac	tive/inactiv	ve	,		
Single ended output voltage on CAN_H	V _{CAN_H}	V _{O(rec)}	recessive output voltage		
Single ended output voltage on CAN_L	V _{CAN_L}	_			
Differential output voltage	V _{Diff}	V _{O(dif)}	differential output voltage		
Optional HS-PMA transmit dominant time-out					
Transmit dominant time-out, long	t _{dom}	t _{to(dom)TXD}	TXD dominant time-out time		
Transmit dominant time-out, short	-				
HS-PMA static receiver input characteristics, bus biasing	g active/ina	ictive			
Recessive state differential input voltage range Dominant state differential input voltage range	V _{Diff}	V _{th(RX)dif}	differential receiver threshold voltage		
		V _{rec(RX)}	receiver recessive voltage		
		V _{dom(RX)}	receiver dominant voltage		
HS-PMA receiver input resistance (matching)					
Differential internal resistance	R _{Diff}	R _{i(dif)}	differential input resistance		
Single ended internal resistance	R _{CAN_H} R _{CAN_L}	R _i	input resistance		
Matching of internal resistance	MR	ΔR _i	input resistance deviation		
HS-PMA implementation loop delay requirement		1	-		
Loop delay	t _{Loop}	t _{d(TXDH-RXDH)}	delay time from TXD HIGH to RXD HIGH		
		$t_{d(TXDL-RXDL)}$	delay time from TXD LOW to RXD LOW		

ISO 11898-2:2016		NXP data she	et
Parameter	Notation	Symbol	Parameter
Optional HS-PMA implementation data signal timing required Mbit/s and above 2 Mbit/s up to 5 Mbit/s	uirements	for use with bit	t rates above 1 Mbit/s up to 2
Transmitted recessive bit width @ 2 Mbit/s / @ 5 Mbit/s, intended	t _{Bit(Bus)}	t _{bit(bus)}	transmitted recessive bit width
Received recessive bit width @ 2 Mbit/s / @ 5 Mbit/s	t _{Bit(RXD)}	t _{bit(RXD)}	bit time on pin RXD
Receiver timing symmetry @ 2 Mbit/s / @ 5 Mbit/s	∆t _{Rec}	∆t _{rec}	receiver timing symmetry
HS-PMA maximum ratings of V_{CAN_H} , V_{CAN_L} and V_{Diff}	-		
Maximum rating V _{Diff}	V _{Diff}	V _(CANH-CANL)	voltage between pin CANH and pin CANL
General maximum rating V_{CAN_H} and V_{CAN_L}	V _{CAN_H}	V _x	voltage on pin x
Optional: Extended maximum rating VCAN_H and VCAN_L	V _{CAN_L}		
HS-PMA maximum leakage currents on CAN_H and CAN	_L, unpow	vered	
Leakage current on CAN_H, CAN_L	I _{CAN_H} I _{CAN_L}	IL	leakage current

Table 13. ISO 11898-2:2016 to NXP data sheet parameter conversion ... continued

19 Appendix: TJx144x/TJx146x/TJF1441 family overview

Table 14. Feature overview of the complete TJx144x/TJx146x/TJF1441 family

	Mode	s				Suppl	ies		Data ı	ate	Additional features					
Device ^[1]	Normal	Standby	Sleep	Silent/Listen-only	Selectable Off	VCC pin	VIO pin	VBAT pin	Up to 5 Mbit/s CAN FD	Up to 8 Mbit/s CAN FD ^[2]	Signal improvement ^[3]	Wake-up source recognition ^[4]	Short WUP support [0.5 - 1.8 µs] ^[5]	Single supply pin wake-up ^[6]	TXD dominant timeout	Local diagnostics via ERR_N pin
TJx1441A	•			•		•	•		•						•	
TJx1441B	•			•		•			•						•	
TJx1441D	•			•	•	•			•						•	
TJF1441A	•			•		•	•		•						[7]	
TJx1442A	•	•				•	•		•				•	•	•	
TJx1442B	•	•				•			•				•		•	
TJx1443A	•	•	•	•		•	•	•	•			•	•	•	•	•
TJx1448A	•	•				•	•		•				•	•	•	
TJx1448B	•	•				•			•				•		•	
TJx1448C	•	•				•	•		•			•	•	•	•	
TJx1462A	•	•				•	•		•	•	•		•	•	•	
TJx1462B	•	•				•			•	•	•		•		•	
TJx1463A	•	•	•	•		•	•	•	•	•	•	•	•	•	•	•

TJx: TJA14xxx is AEC-Q100 Grade 1; TJR14xxx is AEC-Q100 Grade 0; TJF1441A is non-automotive grade. Only guaranteed for TJA146x, AEC-Q100 Grade 1. [1]

[2] [3]

CAN FD Signal Improvement Capability (SIC) according to CiA 601-4:2019.

[4] RXD is held LOW after wake-up request, enabling wake-up source recognition.

[5] WUP = wake-up pattern according ISO11898-2:2016.

[6] [7] Only VIO supply needed for wake-up in TJA1442A, TJA1448A, TJA1448C, TJA1462A; only VBAT supply needed for wake-up in TJA1443A, TJA1463A.

Not having TXD dominant timeout allows for very low data rates in non-automotive grade applications.

20 Revision history

Table 15. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
TJA1441 v.2	20211015	Product data sheet	-	TJA1441 v.1
Modifications	 <u>Table 7</u>: table note 7 <u>Table 10</u>: CAN delay 	e 3) and family (<u>Section 19</u>) feature 10 added y timing characteristics revised <i>ity for use in Automotive applicatio</i>		mers revised
TJA1441 v.1	20200812	Product data sheet	-	-

21 Legal information

21.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

Please consult the most recently issued document before initiating or completing a design. [1]

[2] [3] The term 'short data sheet' is explained in section "Definitions".

The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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High-speed CAN transceiver

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